ERRATUM

Mono-silicon Isoelectronic Replacement in CAI2SiX+: van’t Hoff/Le Bel Carbon or Not?

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On page 121, in the “General feature of CAI2SiX+ (X = Al/Ga/in/Tl)” paragraph, “(see Sch. 2a)” should read “(see Sch. 2b).”

On page 122, in the first paragraph, the first reference to citation 45 should be changed to reference citation 41. In that same paragraph, the second reference to citation 45 should be changed to reference 42.

On page 122, in the second full paragraph, “(see 1b)” should read “(see Sch. 1b).”

On page 124, in the first paragraph, the reference to citation 45 should be changed to reference citation 43. In that same paragraph, the reference to citations 38f,43 should be changed to reference citations 38f,44.

This erratum corrects the printed version of the article, and the online version available on Wiley Online Library. We apologize for the error.